

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

2SC3325

Audio Frequency Low Power Amplifier Applications
Driver Stage Amplifier Applications
Switching Applications

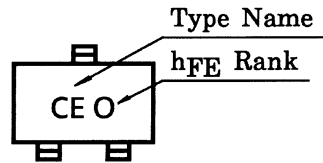
- Excellent hFE linearity: hFE (2) = 25 (min) (VCE = 6 V, IC = 400 mA)
- High voltage: VCEO = 50 V (min)
- Complementary to 2SA1313
- Small package

Absolute Maximum Ratings (Ta = 25°C)

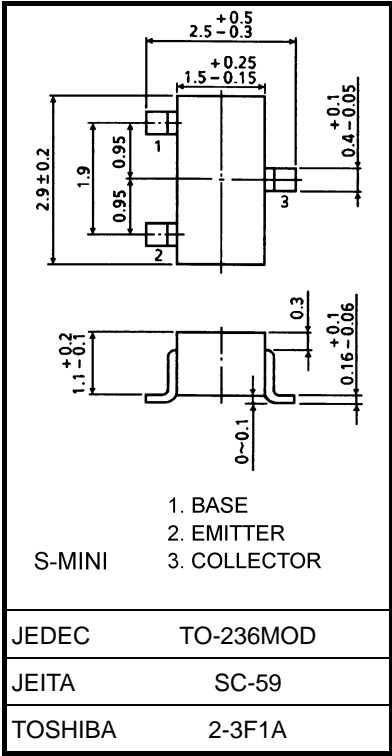
Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	50	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	I _C	500	mA
Base current	I _B	50	mA
Collector power dissipation	P _C	200	mW
Junction temperature	T _j	150	°C
Storage temperature range	T _{stg}	−55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Marking



Unit: mm



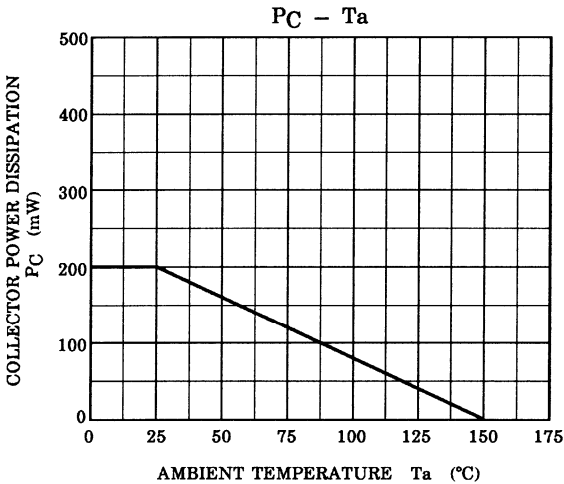
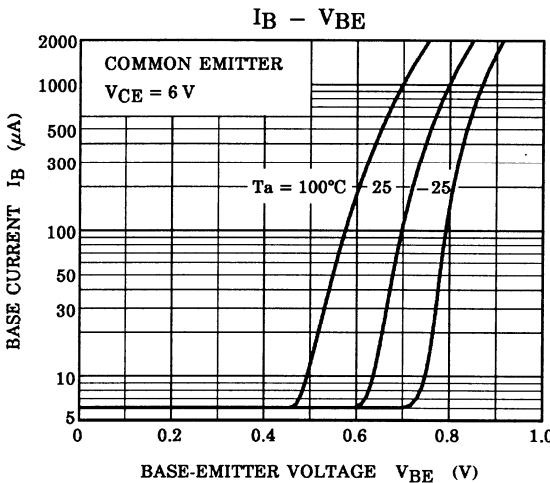
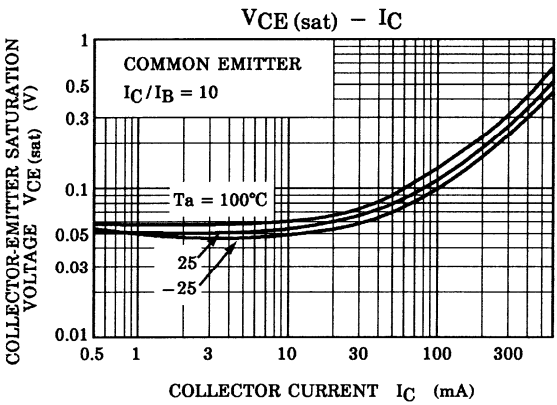
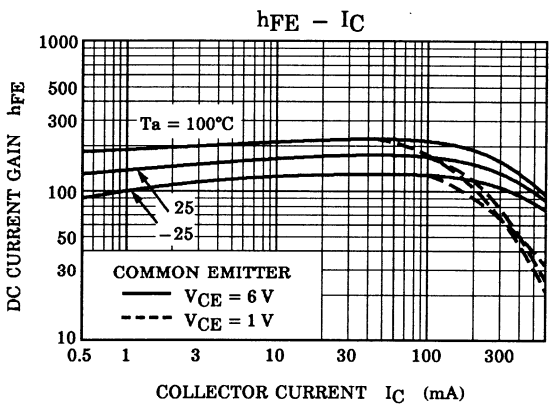
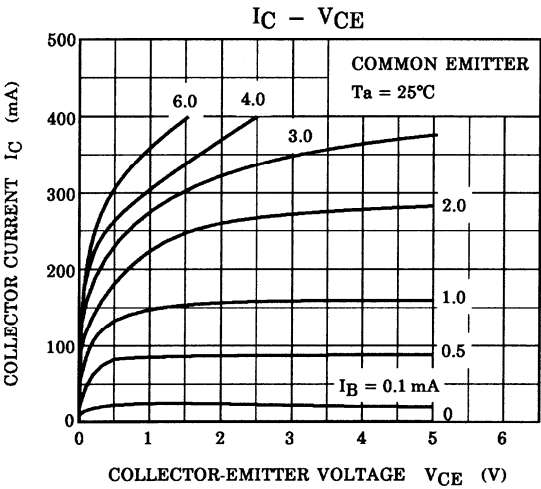
Weight: 0.012 g (typ.)

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = 50\text{ V}, I_E = 0$	—	—	0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 5\text{ V}, I_C = 0$	—	—	0.1	μA
DC current gain	$h_{FE} (1)$ (Note)	$V_{CE} = 1\text{ V}, I_C = 100\text{ mA}$	70	—	240	
	$h_{FE} (2)$ (Note)	$V_{CE} = 6\text{ V}, I_C = 400\text{ mA}$	25	—	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 100\text{ mA}, I_B = 10\text{ mA}$	—	0.1	0.25	V
Base-emitter voltage	V_{BE}	$V_{CE} = 1\text{ V}, I_C = 100\text{ mA}$	—	0.8	1.0	V
Transition frequency	f_T	$V_{CE} = 6\text{ V}, I_C = 20\text{ mA}$	—	300	—	MHz
Collector output capacitance	C_{ob}	$V_{CB} = 6\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	7	—	pF

Note: $h_{FE} (1)$ classification O: 70~140, Y: 120~240

$h_{FE} (2)$ classification O: 25 (min), Y: 40 (min)



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